

Dual N-Channel PowerTrench® MOSFET 60V, 66A, 4.7mΩ

Manufacturers	ON Semiconductor, LLC
Package/Case	PQFN-8
Product Type	Transistors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for FDMD8680 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

This package integrates to N-channel devices connected internally in common-source configuration. This enables very low package parasitics and optimized thermal path to the common source pad on the bottom. Provides a very small footprint (5 x 6 mm) for higher power density.

Features

Common source configuration to Eliminate PCB Routing

Large Source Pad on Bottom of Package for Enhanced Thermals

Max == 10 V,>

Max == 8 V,>

Ideal for Flexible Layout in Secondary Side Synchronous Rectification

100% UIL Tested

Termination is Lead-free and RoHS Compliant

Application

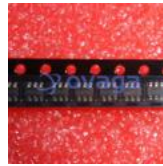
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Related Products



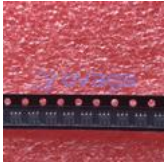
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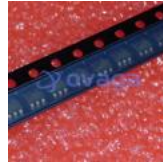
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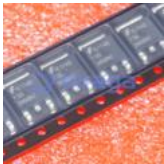
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